



**TECHNICAL SPECIFICATIONS OF SURFACE MOUNT
FAST RECOVERY RECTIFIER
VOLTAGE RANGE - 50 to 1000 Volts CURRENT - 1.0 Ampere**



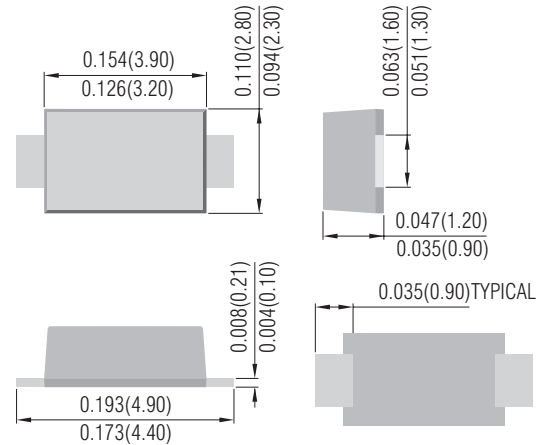
SMF Unit:inch(mm)

FEATURES

- Ideal for surface mounted applications
- Low leakage current
- Glass passivated junction
- High temperature soldering : 260°C /10 seconds at terminals
- Pb free product at available : 99% Sn above meet RoHS environment substance directive request.

MECHANICAL DATA

- Case: Molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: As marked
- Mounting position: Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	SYMBOL	R1A	R1B	R1D	R1G	R1J	R1K	R1M	UNITS
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Rectified Current at TA = 55 °C	IO	1.0							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	30							Amps
Maximum Forward Voltage at 1.0A DC	VF	1.3							Volts
Maximum DC Reverse Current at @TA = 25 °C	IR	5.0							uAmps
Rated DC Blocking Voltage @TA = 125 °C		150							
Maximum Reverse Recovery Time (Note 3)	trr	150				250	500	nSec	
Maximum Thermal Resistance (Note 2)	RθJA	30							°C / W
Typical JunctionCapacitance (Note 1)	CJ	15							pF
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150							°C

- NOTES :**
1. Measured at 1.0 MHz and applied reverse voltage of 4.0VDC
 2. Thermal Resistance (Junction to Ambient), .24in (6.0mm) 2 copper pads to each terminal.
 3. Test Conditions: IF = 0.5A, IR = 1.0A, IRR = 0.25A

DEVICE CHARACTERISTICS

R1A THRU R1M

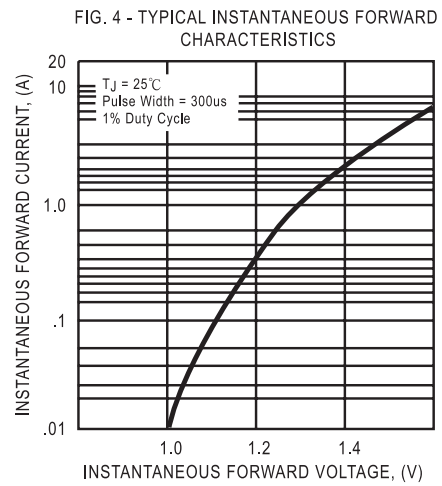
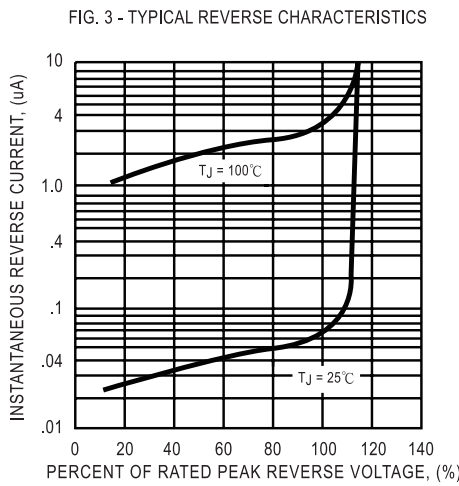
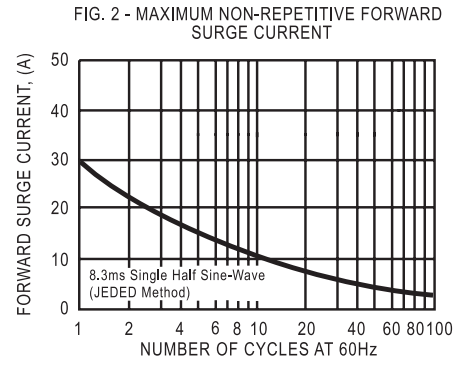
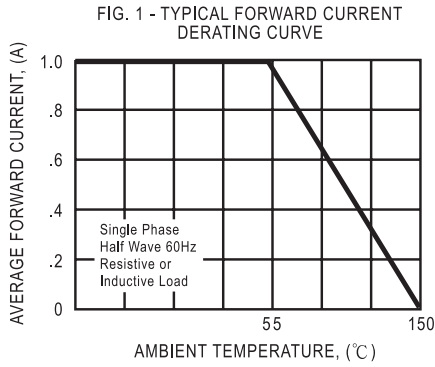
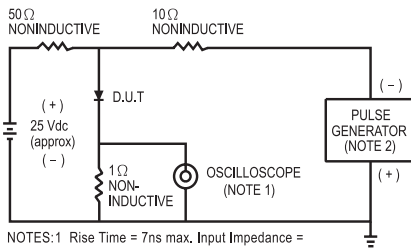


FIG. 5 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. Rise Time = 7ns max. Input Impedance = 1 megohm, 22 pF.
2. Rise Time = 10ns max. Source Impedance = 50 ohms.

